

CYStech Electronics Corp.

Spec. No.: C337SC Issued Date: 2003.06.02

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5.0Amp. Surface Mount Schottky Barrier Diodes

CSMC520-5100SC Series

Features

- For surface mounted applications.
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- Plastic material used carries Underwriters Laboratory Flammability Classification 94V-0
- Low leakage current
- High surge capability
- High temperature soldering: 250°C/10 seconds at terminals
- Exceeds environmental standards of MIL-S-19500/228

Mechanical Data

- Case: Molded plastic, SMC/JEDEC DO-214AB.
- Terminals: Solder plated, solderable per MIL-STD-750 method 2026
- Polarity: Indicated by cathode band.
- Mounting Position : Any.
- Weight: 0.195 gram, 0.00585 ounce

Maximum Ratings and Electrical Characteristics

(Rating at 25°C ambient temperature unless otherwise specified.)

		Type							
Parameter	Symbol	CSMC	CSMC	CSMC	CSMC	CSMC	CSMC	CSMC	Units
		520	530	540	550	560	580	5100	
Repetitive peak reverse voltage	Vrrm	20	30	40	50	60	80	100	V
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	56	70	V
Maximum DC blocking voltage	Vr	20	30	40	50	60	80	100	V
Maximum instantaneous forward voltage, IF=5A (Note 1)	V_{F}	0.55	0.55	0.55	0.7	0.7	0.85	0.85	V
Average forward rectified current	Io 5						Α		
Peak forward surge current @8.3ms single half sine wave superimposed on rated load (JEDEC method)				150					A
Maximum DC reverse current $V_R = V_{RRM}, T_A = 25 ^{\circ} C \text{ (Note 1)}$ $V_R = V_{RRM}, T_A = 125 ^{\circ} C \text{ (Note 1)}$	I_R	0.5 50						mA mA	
Maximum thermal resistance, Junction to ambient(Note 2)	Rth,JA	55 (typ)					°C/W		
Diode junction capacitance @ f=1MHz and applied 4VDC reverse voltage	Сл	380(typ)						pF	
Storage temperature	Tstg	- 55 ∼ +150						$^{\circ}\!\mathbb{C}$	
Operating temperature	TJ	-55 ~ +125						$^{\circ}\!\mathbb{C}$	

Notes : 1. Pulse test, pulse width=300 μ sec, 2% duty cycle

2 .Mounted on PCB with 30mm² (0.013mm thickness) copper pad area.



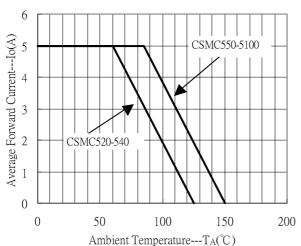
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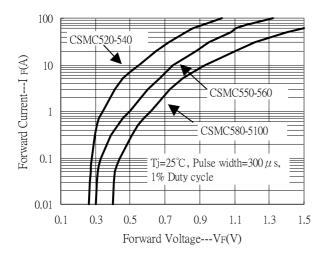
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Characteristic Curves

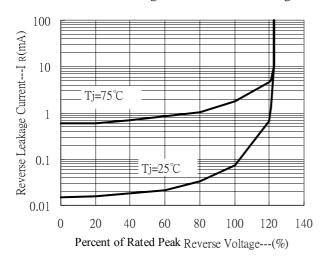
Forward Current Derating Curve



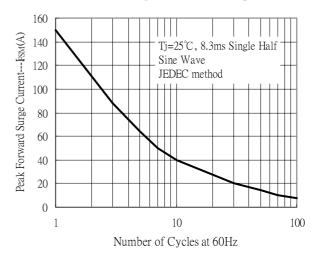
Forward Current vs Forward Voltage



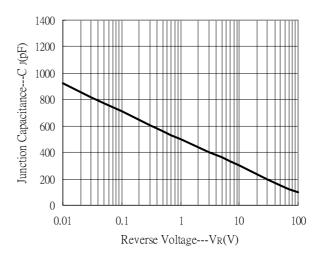
Reverse Leakage Current vs Reverse Voltage



Maximum Non-Repetitive Forward Surge Current



Junction Capacitance vs Reverse Voltage



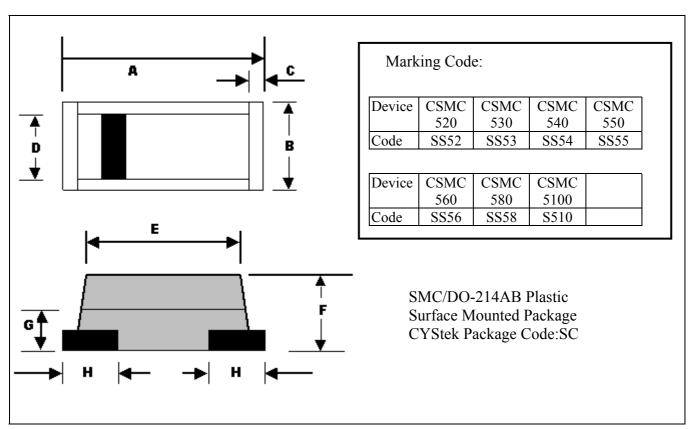


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SMC/DO-214AB Dimension



*:Typical

DIM -	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.	וווט	Min.	Max.	Min.	Max.
Α	0.260	0.276	6.6	7.0	Е	0.228	0.244	5.8	6.2
В	0.173	0.189	4.4	4.8	F	0.071	0.087	1.8	2.2
С	0.012(typ) 0.		0.3(.3(typ) G		0.032(typ)		0.8(typ)	
D	0.144	0.152	3.6	3.8	Н	0.04(typ)		1.0(typ)	

Notes: 1.Controlling dimension: millimeters.

2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material. 3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

• Lead : 42 Alloy ; solder plating

• Mold Compound : Epoxy resin family, flammability solid burning class:UL94V-0

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